NSN 5961-01-156-0044

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-156-0044 **Inclosure Material:** Metal **Overall Length:** Between 2.795 inches and 2.995 inches **Overall Height:** Between 0.860 inches and 0.920 inches **Overall Width:** Between 0.640 inches and 0.700 inches **Function For Which Designed:** Transient suppressor **Mounting Facility Quantity: Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 36.0 breakdown voltage, dc **Current Rating Per Characteristic:** 300.00 amperes forward current, average preset **Test Data Document:** 13160-7566265 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 turret Shelf Life: N/a **Unit Of Measure: Demilitarization:** No